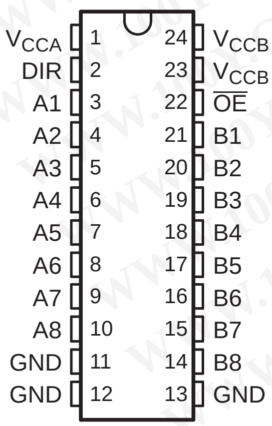
TEXAS INSTRUMENTS
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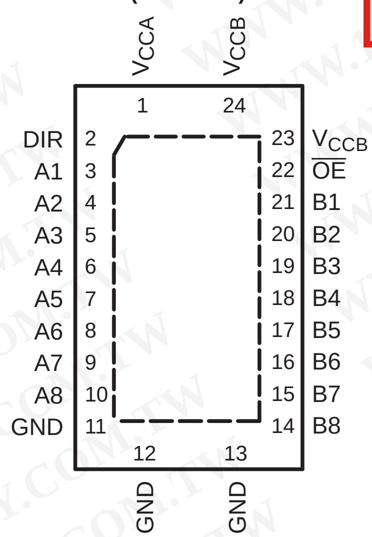
FEATURES

- Control Inputs V_{IH}/V_{IL} Levels Are Referenced to V_{CCA} Voltage
- V_{CC} Isolation Feature – If Either V_{CC} Input Is at GND, All I/O Ports Are in the High-Impedance State
- I_{off} Supports Partial Power-Down-Mode Operation
- Fully Configurable Dual-Rail Design Allows Each Port to Operate Over the Full 1.4-V to 3.6-V Power-Supply Range
- I/Os Are 4.6-V Tolerant
- Max Data Rates
  - 170 Mbps (V_{CCA} < 1.8 V or V_{CCB} < 1.8 V)
  - 320 Mbps ($V_{CCA} \geq$ 1.8 V and $V_{CCB} \geq$ 1.8 V)
- Latch-Up Performance Exceeds 100 mA Per JESD 78, Class II
- ESD Protection Exceeds JESD 22
  - 8000-V Human-Body Model (A114-A)
  - 200-V Machine Model (A115-A)
  - 1000-V Charged-Device Model (C101)

DGV OR PW PACKAGE
(TOP VIEW)



RHL PACKAGE
(TOP VIEW)



DESCRIPTION/ORDERING INFORMATION

This 8-bit noninverting bus transceiver uses two separate configurable power-supply rails. The SN74AVC8T245 is optimized to operate with V_{CCA}/V_{CCB} set at 1.4 V to 3.6 V. It is operational with V_{CCA}/V_{CCB} as low as 1.2 V. The A port is designed to track V_{CCA}. V_{CCA} accepts any supply voltage from 1.2 V to 3.6 V. The B port is designed to track V_{CCB}. V_{CCB} accepts any supply voltage from 1.2 V to 3.6 V. This allows for universal low-voltage bidirectional translation between any of the 1.2-V, 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes.

ORDERING INFORMATION

T_A	PACKAGE(1)		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 85°C	QFN – RHL	Reel of 1000	SN74AVC8T245RHLR	WE245
	TSSOP – PW	Tube of 60	SN74AVC8T245PW	WE245
		Reel of 2000	SN74AVC8T245PWR	
	TVSOP – DGV	Reel of 2000	SN74AVC8T245DGVR	WE245

(1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI website at www.ti.com.

DESCRIPTION/ORDERING INFORMATION (CONTINUED)

The SN74AVC8T245 is designed for asynchronous communication between data buses. The device transmits data from the A bus to the B bus or from the B bus to the A bus, depending on the logic level at the direction-control (DIR) input. The output-enable ($\overline{OE}$) input can be used to disable the outputs so the buses are effectively isolated.

The SN74AVC8T245 is designed so the control pins (DIR and $\overline{OE}$) are supplied by V_{CCA}.

The SN74AVC8T245 solution is compatible with a single-supply system and can be replaced later with a '245 function, with minimal printed circuit board redesign.

This device is fully specified for partial-power-down applications using I_{off}. The I_{off} circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

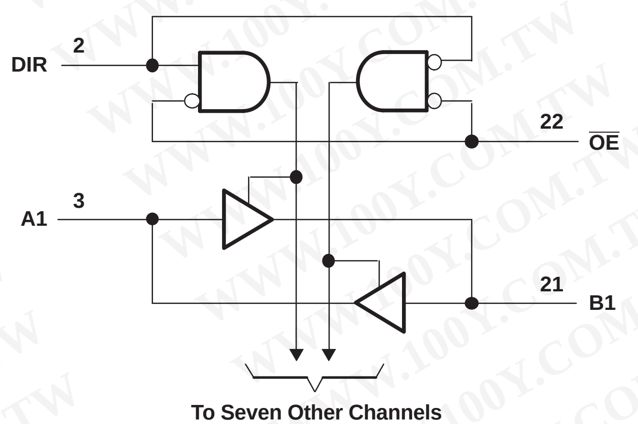
The V_{CC} isolation feature ensures that if either V_{CC} input is at GND, both ports are in the high-impedance state.

To ensure the high-impedance state during power up or power down, $\overline{OE}$ shall be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

FUNCTION TABLE
(each 8-bit section)

INPUTS		OPERATION
$\overline{OE}$	DIR	
L	L	B data to A bus
L	H	A data to B bus
H	X	All outputs Hi-Z

LOGIC DIAGRAM (POSITIVE LOGIC)



Absolute Maximum Ratings[1]

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
V_{CCA}, V_{CCB}	Supply voltage range		–0.5	4.6	V
V_I	Input voltage range[2]	I/O ports (A port)	–0.5	4.6	V
		I/O ports (B port)	–0.5	4.6	
		Control inputs	–0.5	4.6	
V_O	Voltage range applied to any output in the high-impedance or power-off state[2]	A port	–0.5	4.6	V
		B port	–0.5	4.6	
V_O	Voltage range applied to any output in the high or low state[2][3]	A port	–0.5	V_{CCA} + 0.5	V
		B port	–0.5	V_{CCB} + 0.5	
I_{IK}	Input clamp current	V_I < 0		–50	mA
I_{OK}	Output clamp current	V_O < 0		–50	mA
I_O	Continuous output current			±50	mA
	Continuous current through V_{CCA}, V_{CCB}, or GND			±100	mA
θ_{JA}	Package thermal impedance[4]	DGV package		86	°C/W
		PW package		88	
		RHL package		43	
T_{stg}	Storage temperature range		–65	150	°C

(1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
(2) The input voltage and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.
(3) The output positive-voltage rating may be exceeded up to 4.6 V maximum if the output current rating is observed.
(4) The package thermal impedance is calculated in accordance with JESD 51-7.

Recommended Operating Conditions[1][2][3]

			V_{CCI}	V_{CCO}	MIN	MAX	UNIT
V_{CCA}	Supply voltage				1.2	3.6	V
V_{CCB}	Supply voltage				1.2	3.6	V
V_{IH}	High-level input voltage	Data inputs	1.2 V to 1.95 V		$V_{CCI} \times 0.65$		V
			1.95 V to 2.7 V		1.6		
			2.7 V to 3.6 V		2		
V_{IL}	Low-level input voltage	Data inputs	1.2 V to 1.95 V			$V_{CCI} \times 0.35$	V
			1.95 V to 2.7 V			0.7	
			2.7 V to 3.6 V			0.8	
V_{IH}	High-level input voltage	DIR (referenced to V_{CCA})	1.2 V to 1.95 V		$V_{CCA} \times 0.65$		V
			1.95 V to 2.7 V		1.6		
			2.7 V to 3.6 V		2		
V_{IL}	Low-level input voltage	DIR (referenced to V_{CCA})	1.2 V to 1.95 V			$V_{CCA} \times 0.35$	V
			1.95 V to 2.7 V			0.7	
			2.7 V to 3.6 V			0.8	
V_I	Input voltage				0	3.6	V
V_O	Output voltage	Active state			0	V_{CCO}	V
		3-state			0	3.6	
I_{OH}	High-level output current			1.2 V		–3	mA
				1.4 V to 1.6 V		–6	
				1.65 V to 1.95 V		–8	
				2.3 V to 2.7 V		–9	
				3 V to 3.6 V		–12	
I_{OL}	Low-level output current			1.2 V		3	mA
				1.4 V to 1.6 V		6	
				1.65 V to 1.95 V		8	
				2.3 V to 2.7 V		9	
				3 V to 3.6 V		12	
$\Delta t/\Delta v$	Input transition rise or fall rate					5	ns/V
T_A	Operating free-air temperature				–40	85	°C

(1) V_{CCI} is the V_{CC} associated with the input port.
(2) V_{CCO} is the V_{CC} associated with the output port.
(3) All unused data inputs of the device must be held at V_{CCI} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

Electrical Characteristics[1][2]

over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS		V_{CCA}	V_{CCB}	T_A = 25°C			–40°C to 85°C		UNIT
						MIN	TYP	MAX	MIN	MAX	
V_{OH}		I_{OH} = –100 µA	$V_I = V_{IH}$	1.2 V to 3.6 V	1.2 V to 3.6 V				V_{CCO} – 0.2		V
		I_{OH} = –3 mA		1.2 V	1.2 V		0.95				
		I_{OH} = –6 mA		1.4 V	1.4 V				1.05		
		I_{OH} = –8 mA		1.65 V	1.65 V				1.2		
		I_{OH} = –9 mA		2.3 V	2.3 V				1.75		
		I_{OH} = –12 mA		3 V	3 V				2.3		
V_{OL}		I_{OL} = 100 µA	$V_I = V_{IL}$	1.2 V to 3.6 V	1.2 V to 3.6 V					0.2	V
		I_{OL} = 3 mA		1.2 V	1.2 V		0.15				
		I_{OL} = 6 mA		1.4 V	1.4 V					0.35	
		I_{OL} = 8 mA		1.65 V	1.65 V					0.45	
		I_{OL} = 9 mA		2.3 V	2.3 V					0.55	
		I_{OL} = 12 mA		3 V	3 V					0.7	
I_I	Control inputs	$V_I = V_{CCA}$ or GND		1.2 V to 3.6 V	1.2 V to 3.6 V		±0.025	±0.25		±1	µA
I_{off}	A or B port	V_I or V_O = 0 to 3.6 V		0 V	0 V to 3.6 V		±0.1	±1		±5	µA
				0 V to 3.6 V	0 V		±0.1	±1		±5	
I_{OZ}[3]	A or B port	$V_O = V_{CCO}$ or GND, $V_I = V_{CCI}$ or GND, $\overline{OE} = V_{IH}$		3.6 V	3.6 V		±0.5	±2.5		±5	µA
I_{CCA}		$V_I = V_{CCI}$ or GND, $I_O = 0$		1.2 V to 3.6 V	1.2 V to 3.6 V					15	µA
				0 V	3.6 V					–2	
				3.6 V	0 V					15	
I_{CCB}		$V_I = V_{CCI}$ or GND, $I_O = 0$		1.2 V to 3.6 V	1.2 V to 3.6 V					15	µA
				0 V	3.6 V					15	
				3.6 V	0 V					–2	
I<Subscript>CCA</Subscript> + I<Subscript>CCB</Subscript>		$V_I = V_{CCI}$ or GND, $I_O = 0$		1.2 V to 3.6 V	1.2 V to 3.6 V					25	µA
C_i	Control inputs	V_I = 3.3 V or GND		3.3 V	3.3 V		3.5			4.5	pF
C_{io}	A or B port	V_O = 3.3 V or GND		3.3 V	3.3 V		6			7	pF

(1) V_{CCO} is the V_{CC} associated with the output port.
(2) V_{CCI} is the V_{CC} associated with the input port.
(3) For I/O ports, the parameter I_{OZ} includes the input leakage current.

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 1.2 V (see Figure 10)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CCB} = 1.2 V	V_{CCB} = 1.5 V	V_{CCB} = 1.8 V	V_{CCB} = 2.5 V	V_{CCB} = 3.3 V	UNIT
			TYP	TYP	TYP	TYP	TYP	
t_{PLH}	A	B	3.1	2.6	2.5	3	3.5	ns
t_{PHL}			3.1	2.6	2.5	3	3.5	
t_{PLH}	B	A	3.1	2.7	2.5	2.4	2.3	ns
t_{PHL}			3.1	2.7	2.5	2.4	2.3	
t_{PZH}	$\overline{OE}$	A	5.3	5.3	5.3	5.3	5.3	ns
t_{PZL}			5.3	5.3	5.3	5.3	5.3	
t_{PZH}	$\overline{OE}$	B	5.1	4	3.5	3.2	3.1	ns
t_{PZL}			5.1	4	3.5	3.2	3.1	
t_{PHZ}	$\overline{OE}$	A	4.8	4.8	4.8	4.8	4.8	ns
t_{PLZ}			4.8	4.8	4.8	4.8	4.8	
t_{PHZ}	$\overline{OE}$	B	4.7	4	4.1	4.3	5.1	ns
t_{PLZ}			4.7	4	4.1	4.3	5.1	

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 1.5 V ± 0.1 V (see Figure 10)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CCB} = 1.2 V	V_{CCB} = 1.5 V ± 0.1 V		V_{CCB} = 1.8 V ± 0.15 V		V_{CCB} = 2.5 V ± 0.2 V		V_{CCB} = 3.3 V ± 0.3 V		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	B	2.7	0.5	5.4	0.5	4.6	0.5	4.9	0.5	6.8	ns
t_{PHL}			2.7	0.5	5.4	0.5	4.6	0.5	4.9	0.5	6.8	
t_{PLH}	B	A	2.6	0.5	5.4	0.5	5.1	0.5	4.7	0.5	4.5	ns
t_{PHL}			2.6	0.5	5.4	0.5	5.1	0.5	4.7	0.5	4.5	
t_{PZH}	$\overline{OE}$	A	3.7	1.1	8.7	1.1	8.7	1.1	8.7	1.1	8.7	ns
t_{PZL}			3.7	1.1	8.7	1.1	8.7	1.1	8.7	1.1	8.7	
t_{PZH}	$\overline{OE}$	B	4.8	1.1	7.6	1.1	7.1	1	5.6	1	5.2	ns
t_{PZL}			4.8	1.1	7.6	1.1	7.1	1	5.6	1	5.2	
t_{PHZ}	$\overline{OE}$	A	3.1	0.5	8.6	0.5	8.6	0.5	8.6	0.5	8.6	ns
t_{PLZ}			3.1	0.5	8.6	0.5	8.6	0.5	8.6	0.5	8.6	
t_{PHZ}	$\overline{OE}$	B	4.1	0.5	8.4	0.5	7.6	0.5	7.2	0.5	7.8	ns
t_{PLZ}			4.1	0.5	8.4	0.5	7.6	0.5	7.2	0.5	7.8	

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 1.8 V ± 0.15 V (see Figure 10)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CCB} = 1.2 V	V_{CCB} = 1.5 V ± 0.1 V		V_{CCB} = 1.8 V ± 0.15 V		V_{CCB} = 2.5 V ± 0.2 V		V_{CCB} = 3.3 V ± 0.3 V		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	B	2.5	0.5	5.1	0.5	4.4	0.5	4	0.5	3.9	ns
t_{PHL}			2.5	0.5	5.1	0.5	4.4	0.5	4	0.5	3.9	
t_{PLH}	B	A	2.5	0.5	4.6	0.5	4.4	0.5	3.9	0.5	3.7	ns
t_{PHL}			2.5	0.5	4.6	0.5	4.4	0.5	3.9	0.5	3.7	
t_{PZH}	$\overline{OE}$	A	3	1	6.8	1	6.8	1	6.8	1	6.8	ns
t_{PZL}			3	1	6.8	1	6.8	1	6.8	1	6.8	
t_{PZH}	$\overline{OE}$	B	4.6	1.1	8.2	1	6.7	0.5	5.1	0.5	4.5	ns
t_{PZL}			4.6	1.1	8.2	1	6.7	0.5	5.1	0.5	4.5	
t_{PHZ}	$\overline{OE}$	A	2.8	0.5	7.1	0.5	7.1	0.5	7.1	0.5	7.1	ns
t_{PLZ}			2.8	0.5	7.1	0.5	7.1	0.5	7.1	0.5	7.1	
t_{PHZ}	$\overline{OE}$	B	3.9	0.5	7.8	0.5	6.9	0.5	6	0.5	5.8	ns
t_{PLZ}			3.9	0.5	7.8	0.5	6.9	0.5	6	0.5	5.8	

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 2.5 V ± 0.2 V (see Figure 10)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CCB} = 1.2 V	V_{CCB} = 1.5 V ± 0.1 V		V_{CCB} = 1.8 V ± 0.15 V		V_{CCB} = 2.5 V ± 0.2 V		V_{CCB} = 3.3 V ± 0.3 V		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	B	2.4	0.5	4.7	0.5	3.9	0.5	3.1	0.5	2.8	ns
t_{PHL}			2.4	0.5	4.7	0.5	3.9	0.5	3.1	0.5	2.8	
t_{PLH}	B	A	3	0.5	4.9	0.5	4	0.5	3.1	0.5	2.9	ns
t_{PHL}			3	0.5	4.9	0.5	4	0.5	3.1	0.5	2.9	
t_{PZH}	$\overline{OE}$	A	2.2	0.5	4.8	0.5	4.8	0.5	4.8	0.5	4.8	ns
t_{PZL}			2.2	0.5	4.8	0.5	4.8	0.5	4.8	0.5	4.8	
t_{PZH}	$\overline{OE}$	B	4.5	1.1	7.9	0.5	6.4	0.5	4.6	0.5	4	ns
t_{PZL}			4.5	1.1	7.9	0.5	6.4	0.5	4.6	0.5	4	
t_{PHZ}	$\overline{OE}$	A	1.8	0.5	5.1	0.5	5.1	0.5	5.1	0.5	5.1	ns
t_{PLZ}			1.8	0.5	5.1	0.5	5.1	0.5	5.1	0.5	5.1	
t_{PHZ}	$\overline{OE}$	B	3.6	0.5	7.1	0.5	6.3	0.5	5.1	0.5	3.9	ns
t_{PLZ}			3.6	0.5	7.1	0.5	6.3	0.5	5.1	0.5	3.9	

Switching Characteristics

over recommended operating free-air temperature range, V_{CCA} = 3.3 V ± 0.3 V (see Figure 10)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V_{CCB} = 1.2 V	V_{CCB} = 1.5 V ± 0.1 V		V_{CCB} = 1.8 V ± 0.15 V		V_{CCB} = 2.5 V ± 0.2 V		V_{CCB} = 3.3 V ± 0.3 V		UNIT
			TYP	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A	B	2.3	0.5	4.5	0.5	3.7	0.5	2.9	0.5	2.5	ns
t_{PHL}			2.3	0.5	4.5	0.5	3.3	0.5	2.9	0.5	2.5	
t_{PLH}	B	A	3.5	0.5	6.8	0.5	3.9	0.5	2.8	0.5	2.5	ns
t_{PHL}			3.5	0.5	6.8	0.5	3.9	0.5	2.8	0.5	2.5	
t_{PZH}	$\overline{OE}$	A	2	0.5	4	0.5	4	0.5	4	0.5	4	ns
t_{PZL}			2	0.5	4	0.5	4	0.5	4	0.5	4	
t_{PZH}	$\overline{OE}$	B	4.5	1.1	7.8	0.5	6.2	0.5	4.5	0.5	3.9	ns
t_{PZL}			4.5	1.1	7.8	0.5	6.2	0.5	4.5	0.5	3.9	
t_{PHZ}	$\overline{OE}$	A	1.7	0.5	4	0.5	4	0.5	4	0.5	4	ns
t_{PLZ}			1.7	0.5	4	0.5	4	0.5	4	0.5	4	
t_{PHZ}	$\overline{OE}$	B	3.4	0.5	6.9	0.5	6	0.5	4.8	0.5	4.2	ns
t_{PLZ}			3.4	0.5	6.9	0.5	6	0.5	4.8	0.5	4.2	

Operating Characteristics

T_A = 25°C

PARAMETER			TEST CONDITIONS	V_{CCA} = V_{CCB} = 1.2 V	V_{CCA} = V_{CCB} = 1.5 V	V_{CCA} = V_{CCB} = 1.8 V	V_{CCA} = V_{CCB} = 2.5 V	V_{CCA} = V_{CCB} = 3.3 V	UNIT
				TYP	TYP	TYP	TYP	TYP	
C_{pdA} (1)	A to B	Outputs enabled	C_L = 0, f = 10 MHz, t_r = t_f = 1 ns	1	1	1	1	1	pF
		Outputs disabled		1	1	1	1	1	
	B to A	Outputs enabled		12	12	12	13	14	
		Outputs disabled		1	1	1	1	1	
C_{pdB} (1)	A to B	Outputs enabled	C_L = 0, f = 10 MHz, t_r = t_f = 1 ns	12	12	12	13	14	pF
		Outputs disabled		1	1	1	1	1	
	B to A	Outputs enabled		1	1	1	1	1	
		Outputs disabled		1	1	1	1	1	

(1) Power dissipation capacitance per transceiver

Table 1. Typical Total Static Power Consumption (I_{CCA} + I_{CCB})

V_{CCB}	V_{CCA}						UNIT
	0 V	1.2 V	1.5 V	1.8 V	2.5 V	3.3 V	
0 V	0	<0.5	<0.5	<0.5	<0.5	<0.5	µA
1.2 V	<0.5	<1	<1	<1	<1	1	
1.5 V	<0.5	<1	<1	<1	<1	1	
1.8 V	<0.5	<1	<1	<1	<1	<1	
2.5 V	<0.5	1	<1	<1	<1	<1	
3.3 V	<0.5	1	<1	<1	<1	<1	

TYPICAL CHARACTERISTICS

Typical Propagation Delay (A to B) vs Load Capacitance
T_A = 25°C, V_{CCA} = 1.2 V

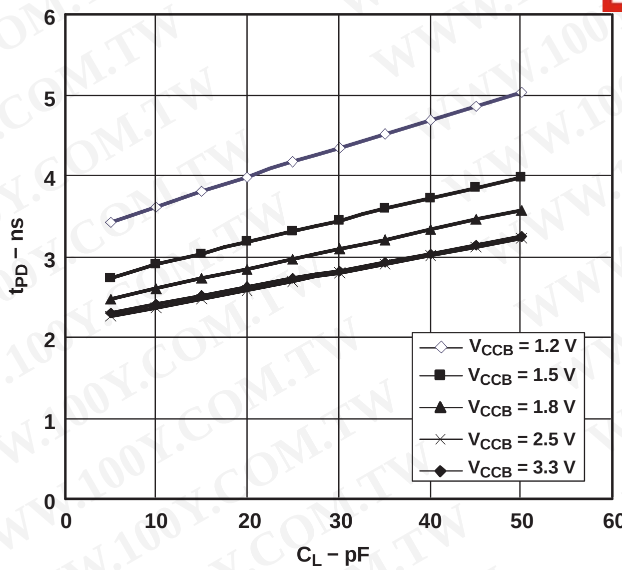


Figure 1.

Typical Propagation Delay (A to B) vs Load Capacitance
T_A = 25°C, V_{CCA} = 1.5 V

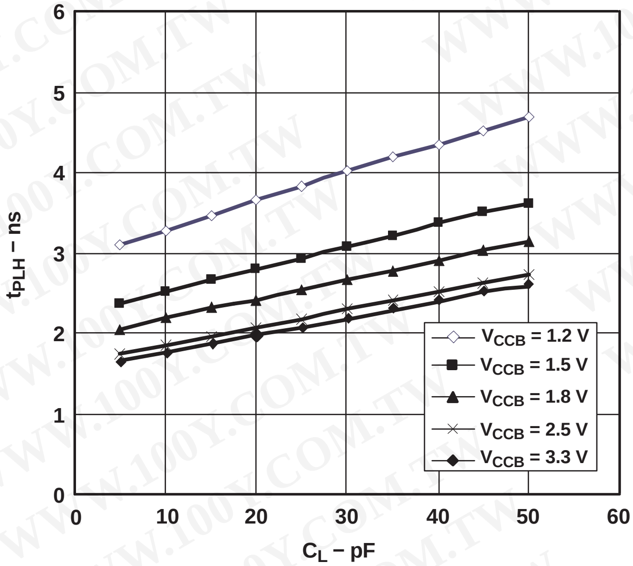


Figure 2.

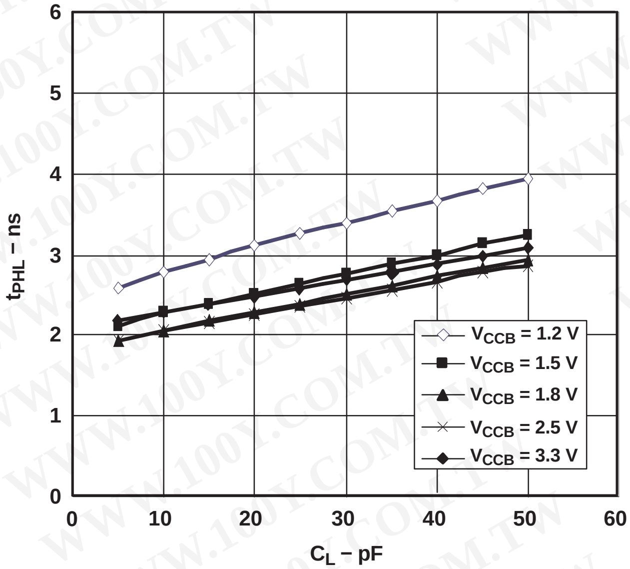


Figure 3.

TYPICAL CHARACTERISTICS (continued)

Typical Propagation Delay (A to B) vs Load Capacitance
T_A = 25°C, V_{CCA} = 1.8 V

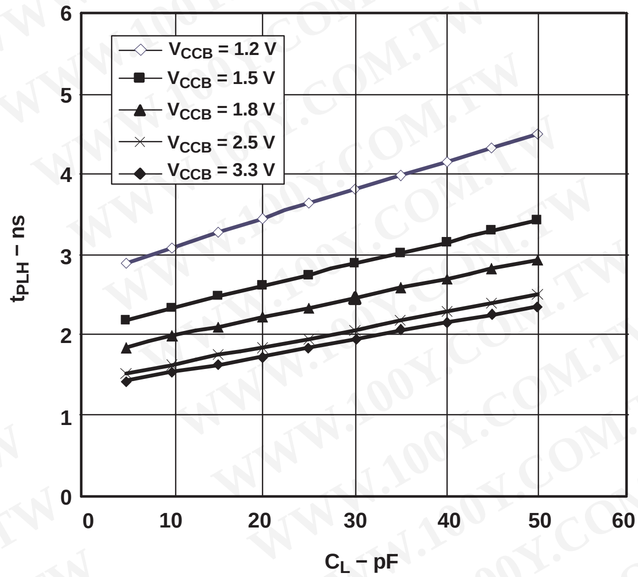


Figure 4.

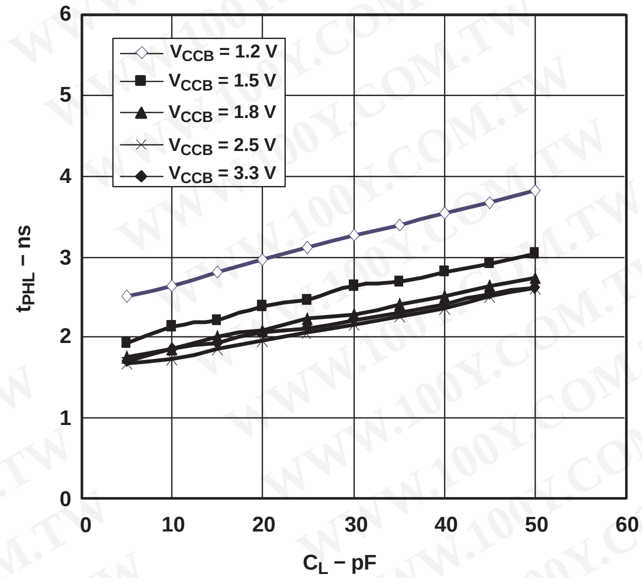


Figure 5.

Typical Propagation Delay (A to B) vs Load Capacitance
T_A = 25°C, V_{CCA} = 2.5 V

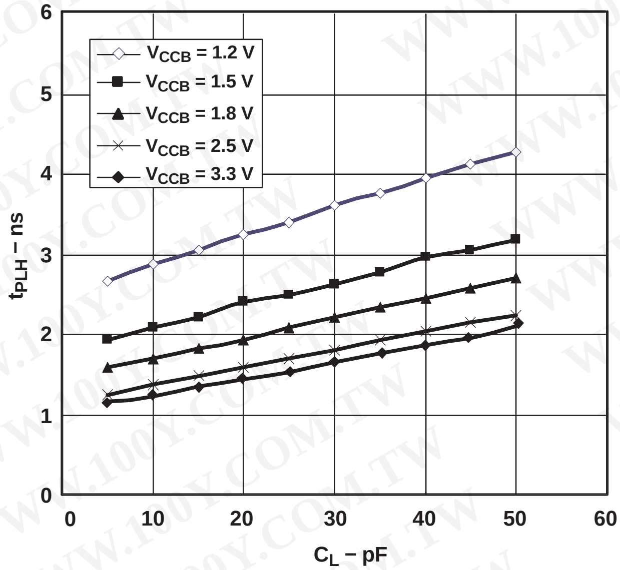


Figure 6.

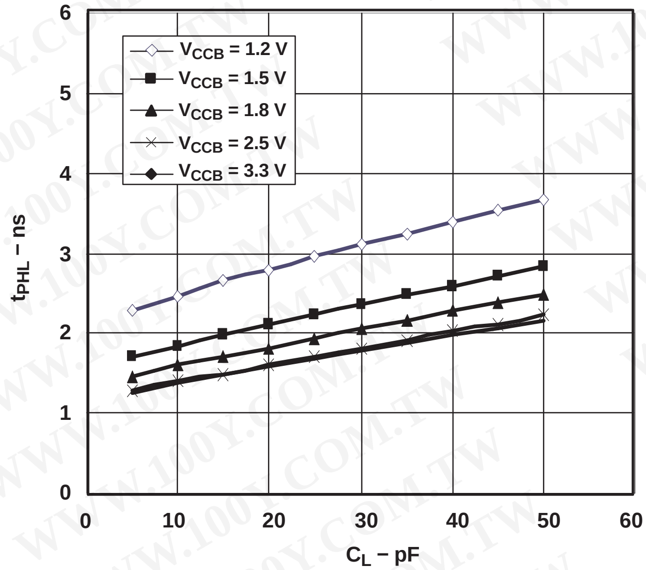


Figure 7.

TYPICAL CHARACTERISTICS (continued)

Typical Propagation Delay (A to B) vs Load Capacitance
$T_A = 25°C$, $V_{CCA} = 3.3$ V

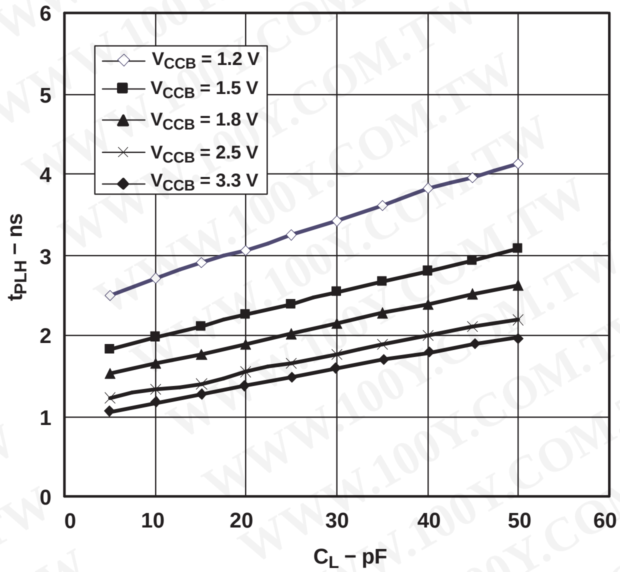


Figure 8.

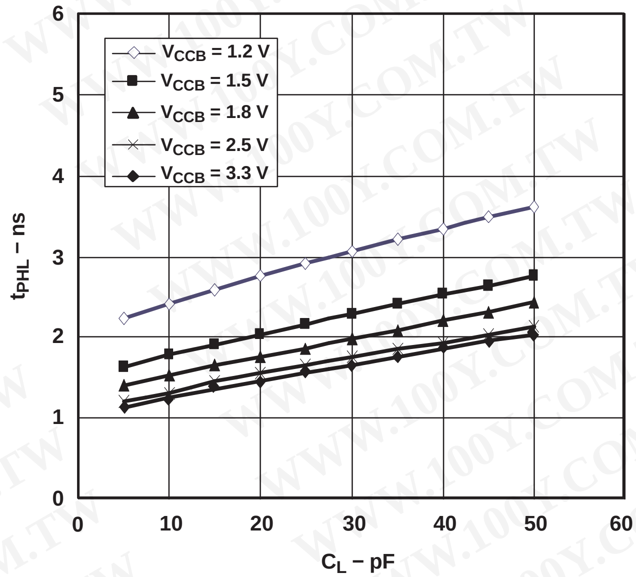
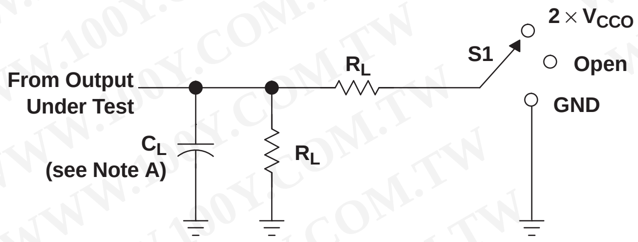


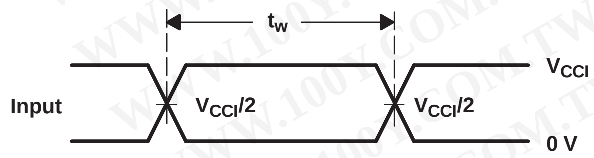
Figure 9.

PARAMETER MEASUREMENT INFORMATION



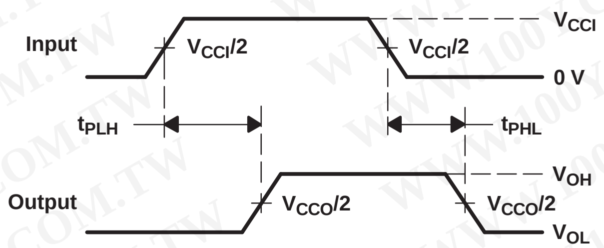
LOAD CIRCUIT

TEST	S1
t_{pd}	Open
t_{PLZ}/t_{PZL}	$2 \times V_{CCO}$
t_{PHZ}/t_{PZH}	GND

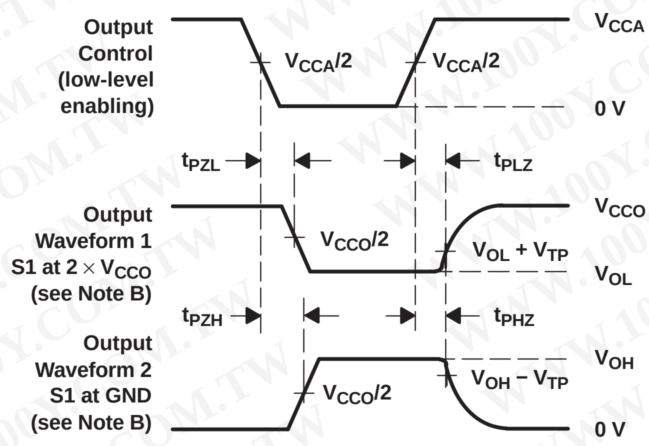


VOLTAGE WAVEFORMS
PULSE DURATION

V_{CCO}	C_L	R_L	V_{TP}
1.2 V	15 pF	2 kΩ	0.1 V
1.5 V ± 0.1 V	15 pF	2 kΩ	0.1 V
1.8 V ± 0.15 V	15 pF	2 kΩ	0.15 V
2.5 V ± 0.2 V	15 pF	2 kΩ	0.15 V
3.3 V ± 0.3 V	15 pF	2 kΩ	0.3 V



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES

NOTES:
A. C_L includes probe and jig capacitance.
B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control.
C. All input pulses are supplied by generators having the following characteristics: PRR ≤ 10 MHz, Z_O = 50 Ω, dv/dt ≥ 1 V/ns.
D. The outputs are measured one at a time, with one transition per measurement.
E. t_{PLZ} and t_{PHZ} are the same as t_{dis}.
F. t_{PZL} and t_{PZH} are the same as t_{en}.
G. t_{PLH} and t_{PHL} are the same as t_{pd}.
H. V_{CCI} is the V_{CC} associated with the input port.
I. V_{CCO} is the V_{CC} associated with the output port.

Figure 10. Load Circuit and Voltage Waveforms

PACKAGING INFORMATION

Orderable Device	Status (1)	Package Type	Package Drawing	Pins	Package Qty	Eco Plan (2)	Lead/Ball Finish	MSL Peak Temp (3)
74AVC8T245DGVRE4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AVC8T245DGVRG4	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74AVC8T245RHLRG4	ACTIVE	QFN	RHL	24	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR
SN74AVC8T245DGVR	ACTIVE	TVSOP	DGV	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC8T245PW	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC8T245PWE4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC8T245PWG4	ACTIVE	TSSOP	PW	24	60	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC8T245PWR	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC8T245PWRE4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC8T245PWRG4	ACTIVE	TSSOP	PW	24	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74AVC8T245RHLR	ACTIVE	QFN	RHL	24	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260C-1 YEAR

(1) The marketing status values are defined as follows:
ACTIVE: Product device recommended for new designs.
LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.
NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.
PREVIEW: Device has been announced but is not in production. Samples may or may not be available.
OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.
TBD: The Pb-Free/Green conversion plan has not been defined.
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.
Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.
Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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to Customer on an annual basis.

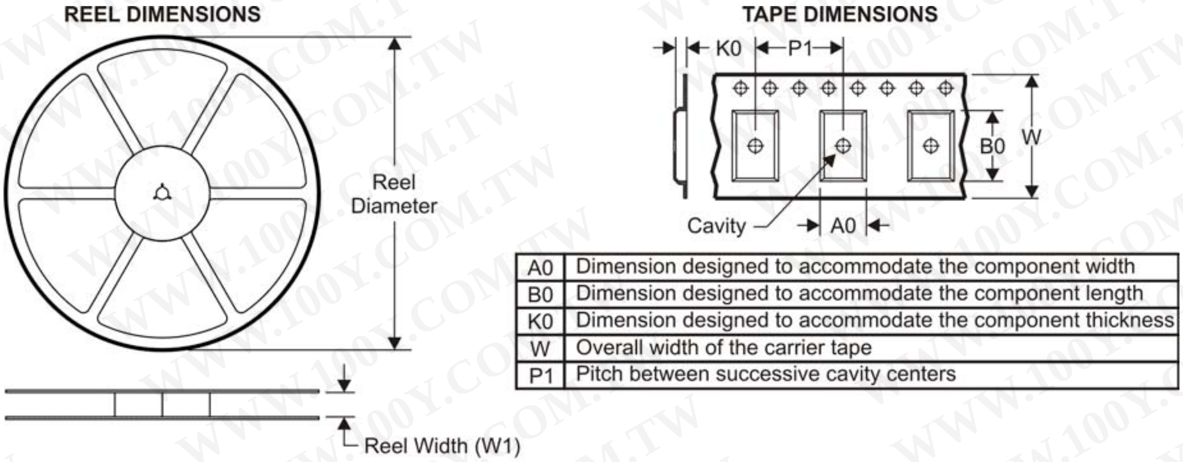
OTHER QUALIFIED VERSIONS OF SN74AVC8T245 :

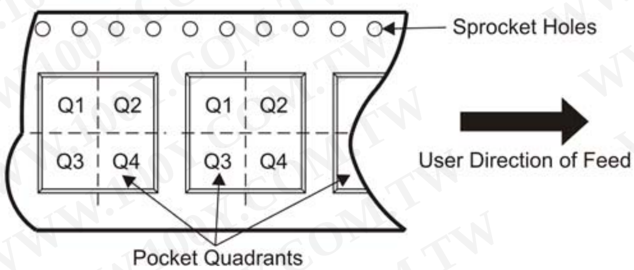
- Automotive: SN74AVC8T245-Q1

NOTE: Qualified Version Definitions:

- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION



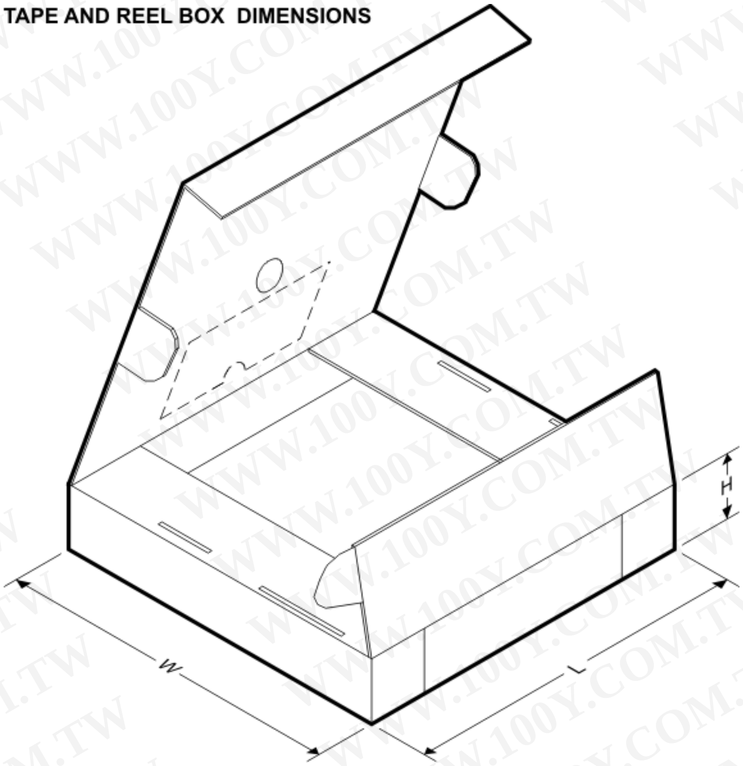


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AVC8T245DGVR	TVSOP	DGV	24	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74AVC8T245PWR	TSSOP	PW	24	2000	330.0	16.4	6.95	8.3	1.6	8.0	16.0	Q1
SN74AVC8T245RHLR	QFN	RHL	24	1000	180.0	12.4	3.8	5.8	1.2	8.0	12.0	Q1



TAPE AND REEL BOX DIMENSIONS

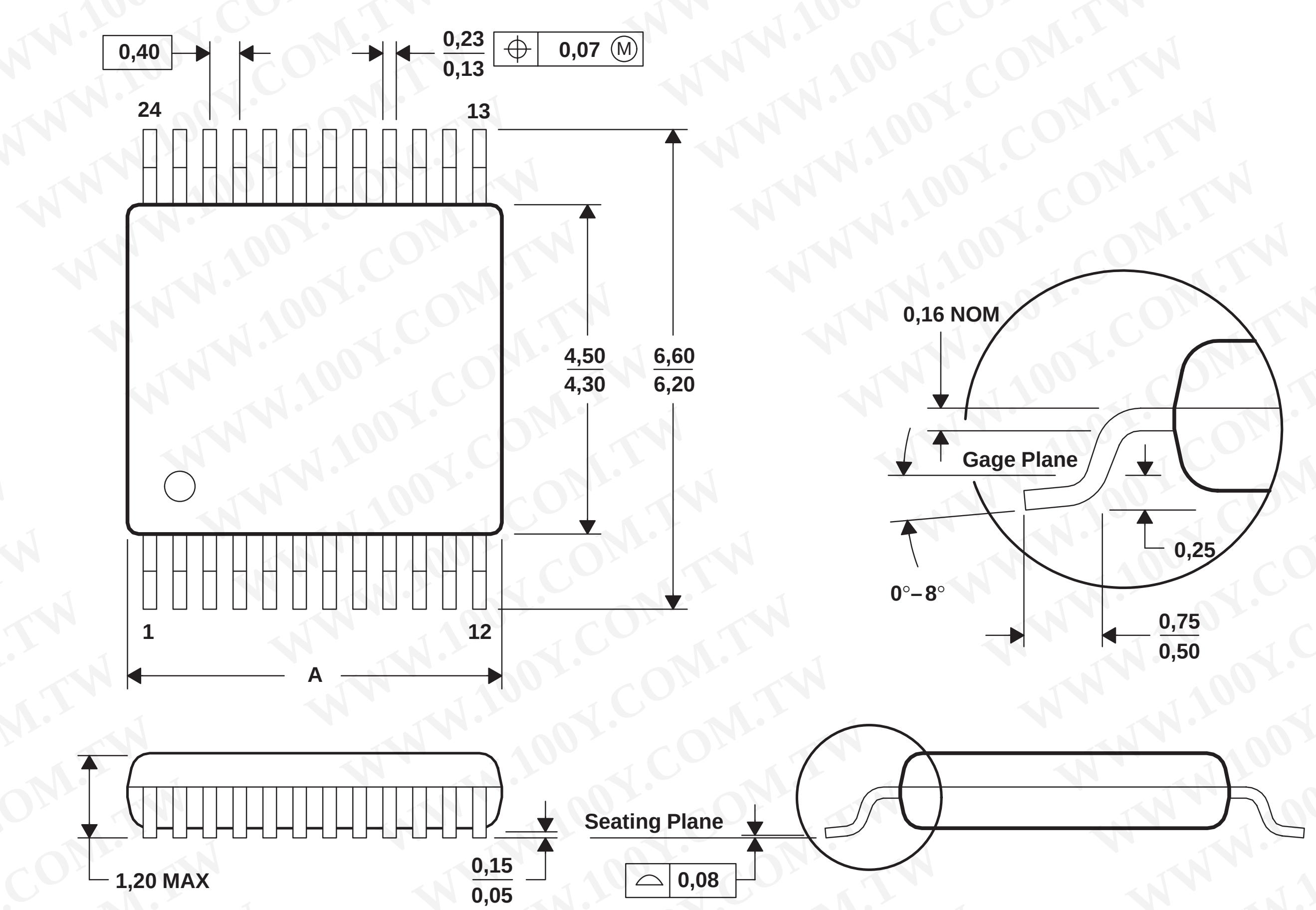


*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74AVC8T245DGVR	TVSOP	DGV	24	2000	346.0	346.0	29.0
SN74AVC8T245PWR	TSSOP	PW	24	2000	346.0	346.0	33.0
SN74AVC8T245RHLR	QFN	RHL	24	1000	190.5	212.7	31.8

DGV (R-PDSO-G)** **PLASTIC SMALL-OUTLINE**

24 PINS SHOWN

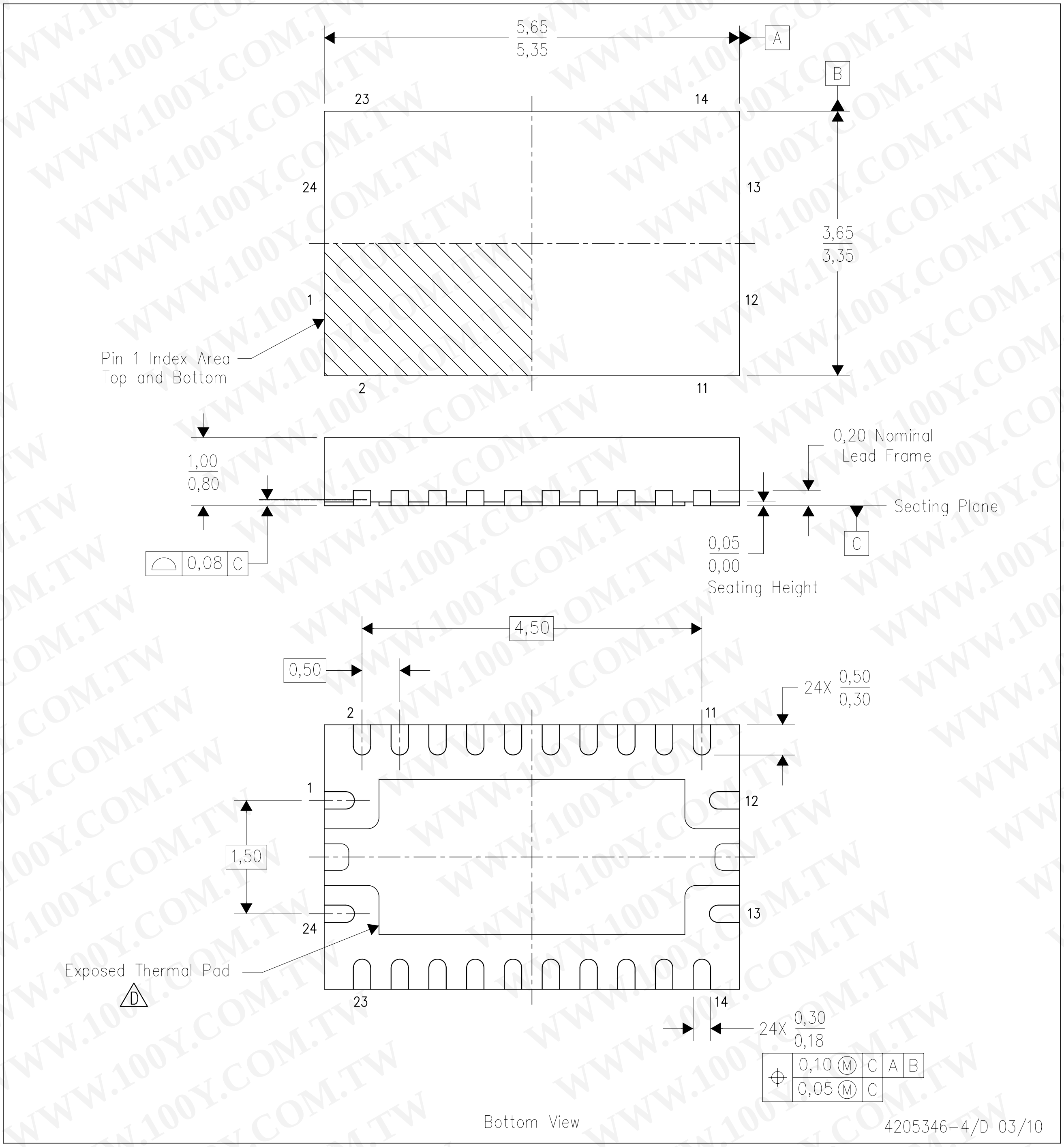


PINS ** / DIM	14	16	20	24	38	48	56
A MAX	3,70	3,70	5,10	5,10	7,90	9,80	11,40
A MIN	3,50	3,50	4,90	4,90	7,70	9,60	11,20

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NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.
D. Falls within JEDEC: 24/48 Pins – MO-153
14/16/20/56 Pins – MO-194

RHL (R–PVQFN–N24) PLASTIC QUAD FLATPACK NO–LEAD



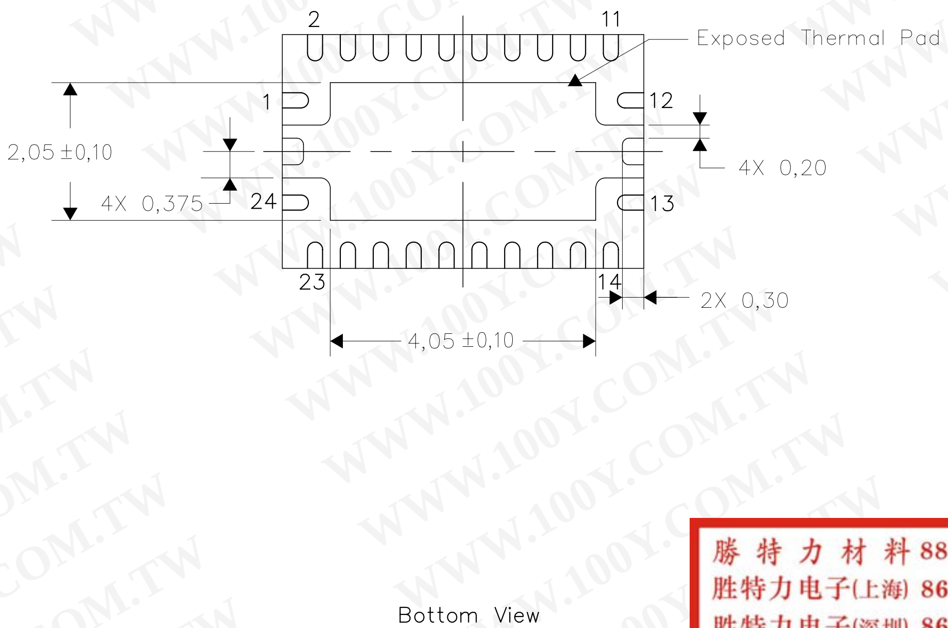
NOTES:
A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M–1994.
B. This drawing is subject to change without notice.
C. QFN (Quad Flatpack No–Lead) package configuration.
D. The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.
E. JEDEC MO–241 package registration pending.

THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No–Lead (QFN) package and its advantages, refer to Application Report, QFN/SON PCB Attachment, Texas Instruments Literature No. SLUA271. This document is available at www.ti.com.

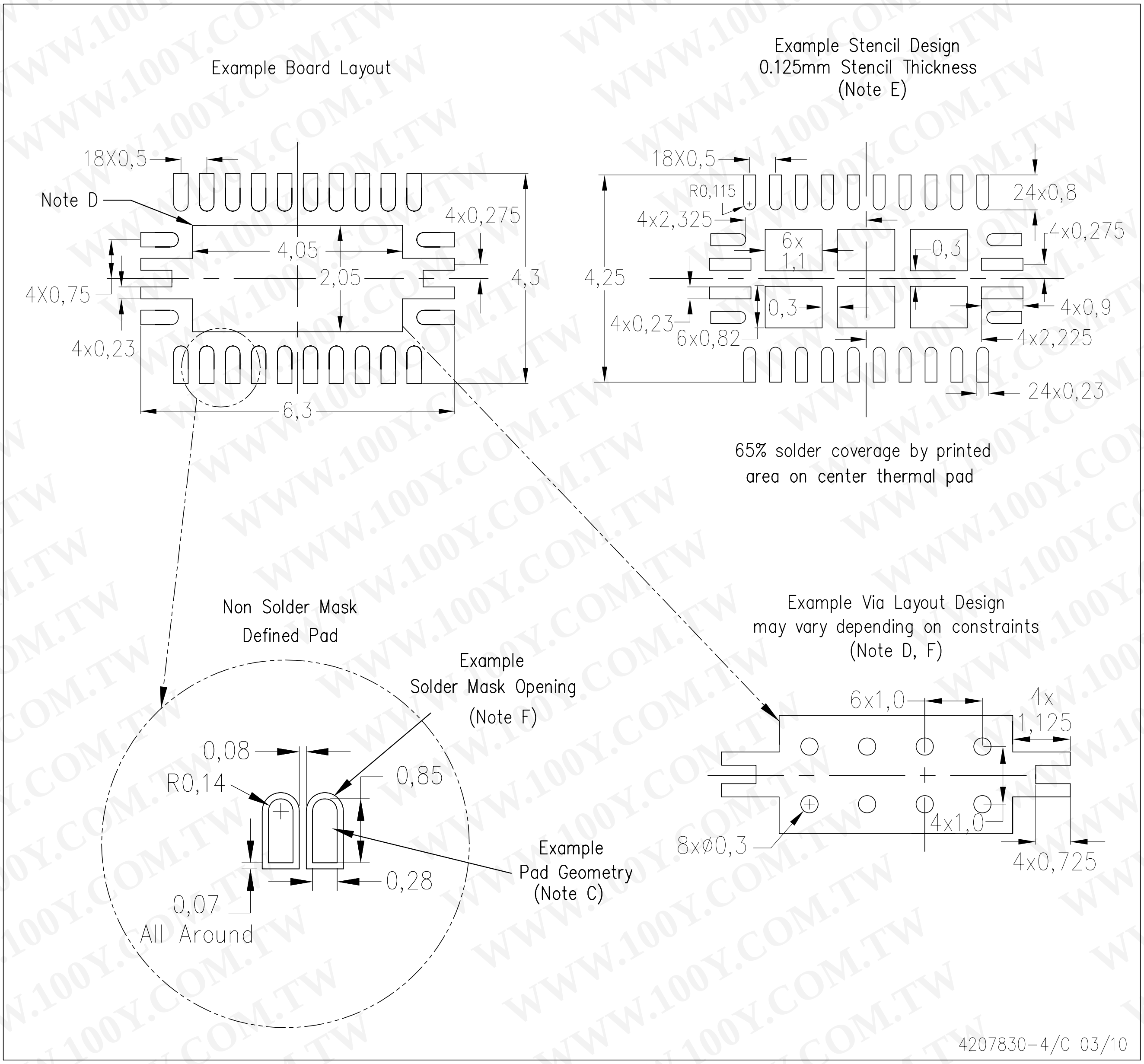
The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

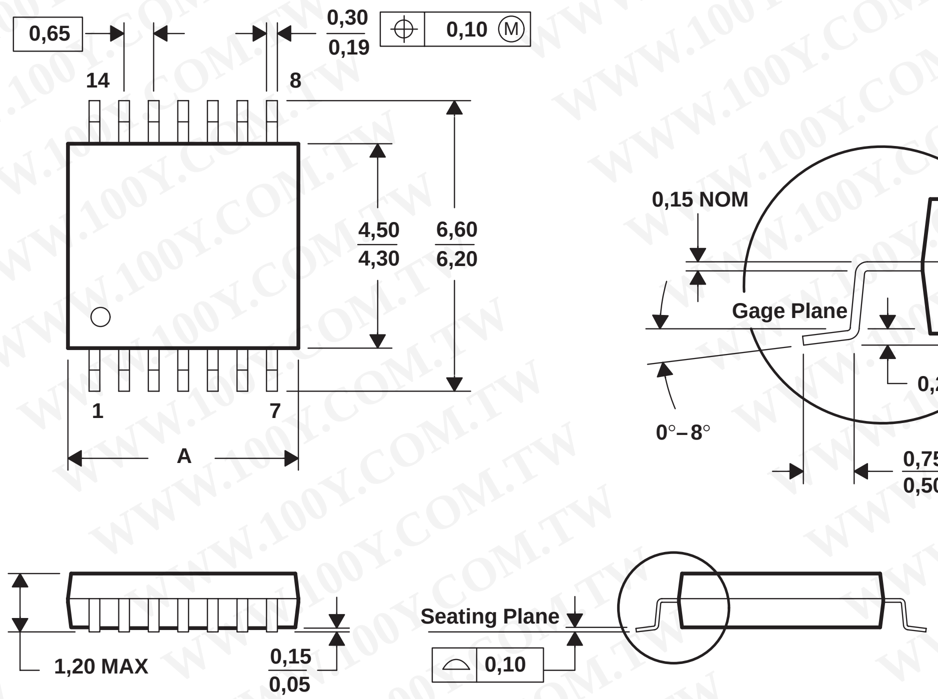
RHL (R–PVQFN–N24) PLASTIC QUAD FLATPACK NO–LEAD



NOTES:
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC–7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat–Pack Packages, Texas Instruments Literature No. SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com <http://www.ti.com>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for minimum solder mask web tolerances between signal pads.

PW (R-PDSO-G)** **PLASTIC SMALL-OUTLINE PACKAGE**

14 PINS SHOWN



PINS ** / DIM	8	14	16	20	24	28
A MAX	3,10	5,10	5,10	6,60	7,90	9,80
A MIN	2,90	4,90	4,90	6,40	7,70	9,60

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NOTES: A. All linear dimensions are in millimeters.
B. This drawing is subject to change without notice.
C. Body dimensions do not include mold flash or protrusion not to exceed 0,15.
D. Falls within JEDEC MO-153